



Company Name	Next Generation Intelligence Semiconductor Foundation	<div>Company Logo</div> 
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Exhibitor Introduction	A project to develop next-generation intelligent semiconductor technology with a total project cost of KRW 1.096 trillion, including KRW 488 billion from the Ministry of Science and ICT ('20-'29) and KRW 521.6 billion from the Ministry of Trade, Industry and Energy ('20-'26).	
Exhibit Description	Future devices to reduce power consumption and realize high performance (Ministry of Science and ICT), design technology to improve calculation speed (Ministry of Science and ICT, Ministry of Trade, Industry and Energy), and atomic-level process and equipment technology to overcome the limitations of miniaturization (Ministry of Trade, Industry and Energy)	
Exhibit Product	Vision & Goal & Overview of project  Introduction to four fields: devices, artificial intelligence design, commercial semiconductor design, and manufacturing equipment	